

SN54LVTH16646, SN74LVTH16646 3.3-V ABT 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

- **Members of the Texas Instruments Widebus™ Family**
- **State-of-the-Art Advanced BiCMOS Technology (ABT) Design for 3.3-V Operation and Low Static-Power Dissipation**
- **Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 3.3-V V_{CC})**
- **Support Unregulated Battery Operation Down to 2.7 V**
- **Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 3.3$ V, $T_A = 25^\circ\text{C}$**
- **I_{off} and Power-Up 3-State Support Hot Insertion**
- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**
- **Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise**
- **Flow-Through Architecture Optimizes PCB Layout**
- **Latch-Up Performance Exceeds 500 mA Per JESD 17**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model ($C = 200$ pF, $R = 0$)**
- **Package Options Include Plastic Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings**

SN54LVTH16646 ... WD PACKAGE
SN74LVTH16646 ... DGG OR DL PACKAGE
(TOP VIEW)

1DIR	1	56	1OE
1CLKAB	2	55	1CLKBA
1SAB	3	54	1SBA
GND	4	53	GND
1A1	5	52	1B1
1A2	6	51	1B2
V_{CC}	7	50	V_{CC}
1A3	8	49	1B3
1A4	9	48	1B4
1A5	10	47	1B5
GND	11	46	GND
1A6	12	45	1B6
1A7	13	44	1B7
1A8	14	43	1B8
2A1	15	42	2B1
2A2	16	41	2B2
2A3	17	40	2B3
GND	18	39	GND
2A4	19	38	2B4
2A5	20	37	2B5
2A6	21	36	2B6
V_{CC}	22	35	V_{CC}
2A7	23	34	2B7
2A8	24	33	2B8
GND	25	32	GND
2SAB	26	31	2SBA
2CLKAB	27	30	2CLKBA
2DIR	28	29	2OE

description

The 'LVTH16646 devices are 16-bit bus transceivers designed for low-voltage (3.3-V) V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment.

These devices can be used as two 8-bit transceivers or one 16-bit transceiver. Data on the A or B bus is clocked into the registers on the low-to-high transition of the appropriate clock (CLKAB or CLKBA) input. Figure 1 illustrates the four fundamental bus-management functions that can be performed with the 'LVTH16646 devices.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments Incorporated.

UNLESS OTHERWISE NOTED this document contains PRODUCTION DATA information current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 1999, Texas Instruments Incorporated



SN54LVTH16646, SN74LVTH16646

3.3-V ABT 16-BIT BUS TRANSCEIVERS

WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

description (continued)

Output-enable (\overline{OE}) and direction-control (DIR) inputs are provided to control the transceiver functions. In the transceiver mode, data present at the high-impedance port may be stored in either register or in both. The select-control (SAB and SBA) inputs can multiplex stored and real-time (transparent mode) data. The circuitry used for select control eliminates the typical decoding glitch that occurs in a multiplexer during the transition between stored and real-time data. DIR determines which bus receives data when \overline{OE} is low. In the isolation mode (\overline{OE} high), A data can be stored in one register and/or B data can be stored in the other register.

When an output function is disabled, the input function is still enabled and can be used to store and transmit data. Only one of the two buses, A or B, can be driven at a time.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

When V_{CC} is between 0 and 1.5 V, the devices are in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.5 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

These devices are fully specified for hot-insertion applications using I_{off} and power-up 3-state. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down. The power-up 3-state circuitry places the outputs in the high-impedance state during power up and power down, which prevents driver conflict.

The SN54LVTH16646 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74LVTH16646 is characterized for operation from -40°C to 85°C .

FUNCTION TABLE

INPUTS						DATA I/O		OPERATION OR FUNCTION
\overline{OE}	DIR	CLKAB	CLKBA	SAB	SBA	A1–A8	B1–B8	
X	X	\uparrow	X	X	X	Input	Unspecified [†]	Store A, B unspecified [†]
X	X	X	\uparrow	X	X	Unspecified [†]	Input	Store B, A unspecified [†]
H	X	\uparrow	\uparrow	X	X	Input	Input	Store A and B data
H	X	H or L	H or L	X	X	Input disabled	Input disabled	Isolation, hold storage
L	L	X	X	X	L	Output	Input	Real-time B data to A bus
L	L	X	H or L	X	H	Output	Input	Stored B data to A bus
L	H	X	X	L	X	Input	Output	Real-time A data to B Bus
L	H	H or L	X	H	X	Input	Output	Stored A data to bus

[†] The data-output functions may be enabled or disabled by various signals at \overline{OE} or DIR. Data-input functions always are enabled, i.e., data at the bus terminals is stored on every low-to-high transition of the clock inputs.

SN54LVTH16646, SN74LVTH16646
3.3-V ABT 16-BIT BUS TRANSCEIVERS
WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

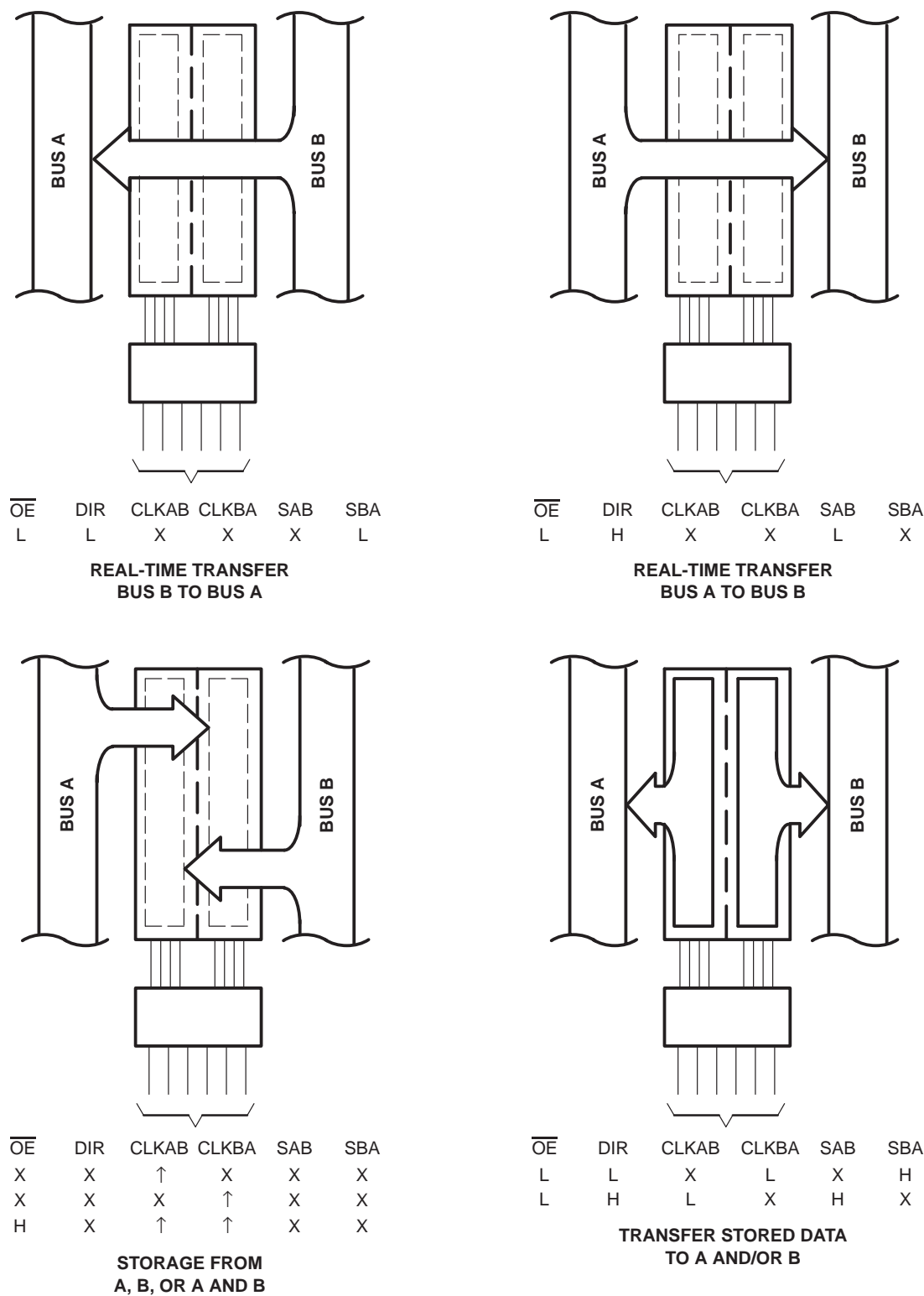
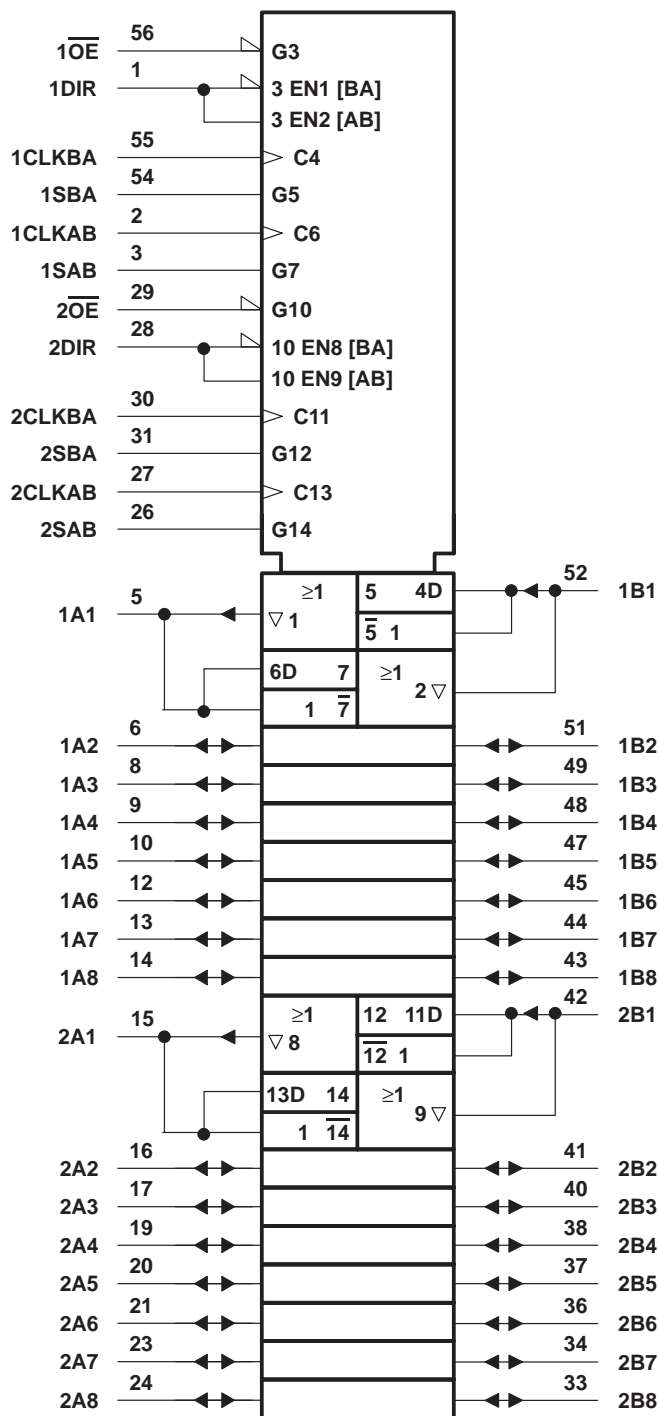


Figure 1. Bus-Management Functions

SN54LVTH16646, SN74LVTH16646 3.3-V ABT 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

logic symbol†

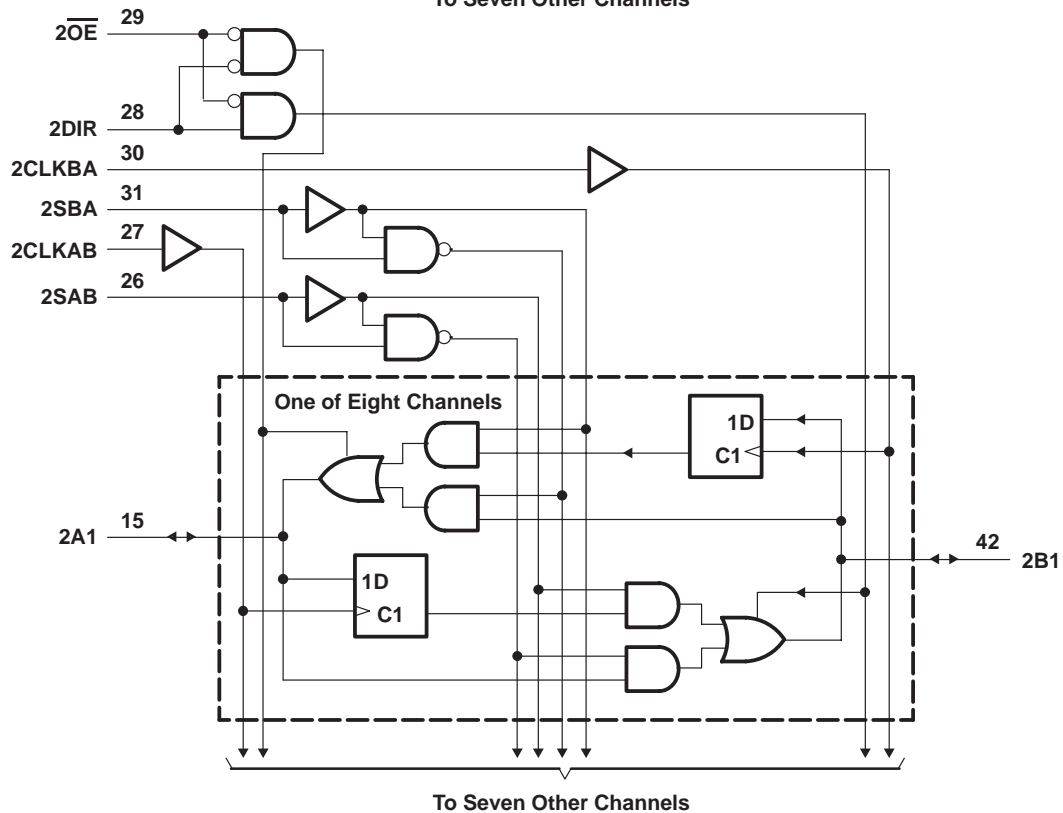
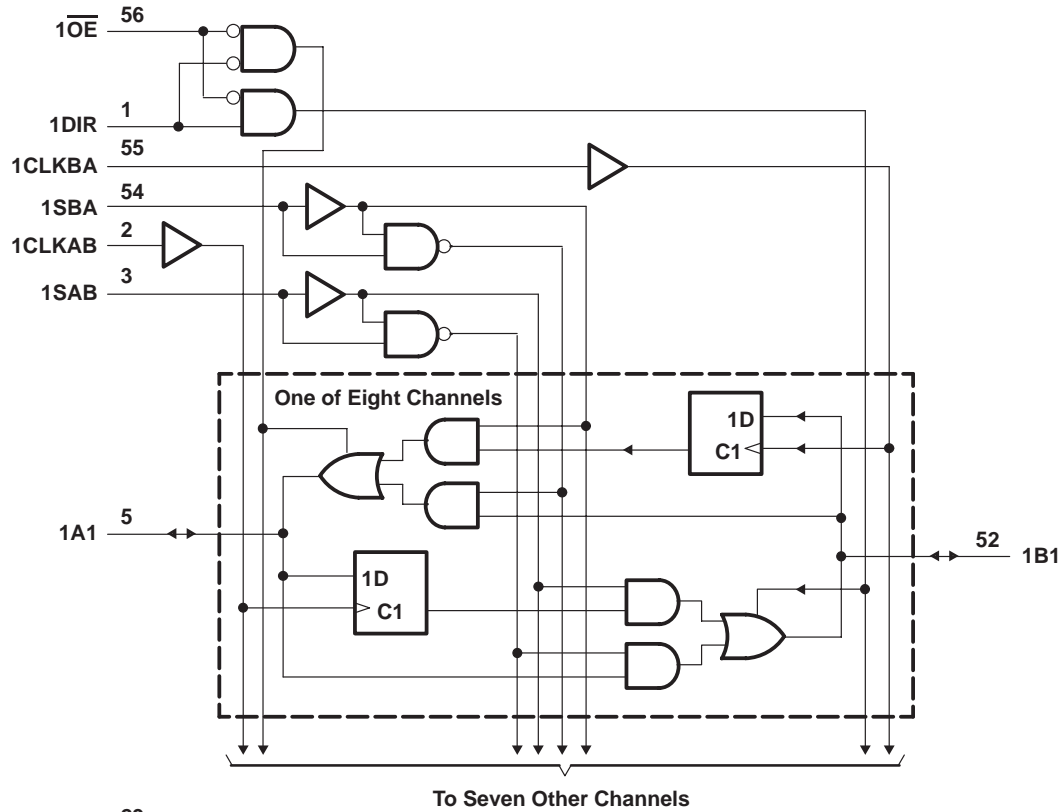


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

SN54LVTH16646, SN74LVTH16646
3.3-V ABT 16-BIT BUS TRANSCEIVERS
WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

logic diagram (positive logic)



SN54LVTH16646, SN74LVTH16646

3.3-V ABT 16-BIT BUS TRANSCEIVERS

WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 4.6 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high-impedance or power-off state, V_O (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high state, V_O (see Note 1)	–0.5 V to $V_{CC} + 0.5$ V
Current into any output in the low state, I_O : SN54LVTH16646	96 mA
SN74LVTH16646	128 mA
Current into any output in the high state, I_O (see Note 2): SN54LVTH16646	48 mA
SN74LVTH16646	64 mA
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Package thermal impedance, θ_{JA} (see Note 3): DGG package	81°C/W
DL package	74°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. This current flows only when the output is in the high state and $V_O > V_{CC}$.
3. The package thermal impedance is calculated in accordance with JESD 51.

recommended operating conditions (see Note 4)

		SN54LVTH16646		SN74LVTH16646		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	2.7	3.6	2.7	3.6	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage		5.5		5.5	V
I_{OH}	High-level output current		–24		–32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled			10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	200		200		μs/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 4: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

SN54LVTH16646, SN74LVTH16646

3.3-V ABT 16-BIT BUS TRANSCEIVERS

WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		SN54LVTH16646			SN74LVTH16646			UNIT		
				MIN	TYP†	MAX	MIN	TYP†	MAX			
V _{IK}		V _{CC} = 2.7 V, I _I = −18 mA		−1.2			−1.2			V		
V _{OH}		V _{CC} = 2.7 V to 3.6 V, I _{OH} = −100 μA		V _{CC} −0.2			V _{CC} −0.2			V		
		V _{CC} = 2.7 V, I _{OH} = −8 mA		2.4			2.4					
		V _{CC} = 3 V		I _{OH} = −24 mA			2					
				I _{OH} = −32 mA			2					
V _{OL}		V _{CC} = 2.7 V		I _{OL} = 100 μA			0.2			V		
				I _{OL} = 24 mA			0.5					
		V _{CC} = 3 V		I _{OL} = 16 mA			0.4					
				I _{OL} = 32 mA			0.5					
				I _{OL} = 48 mA			0.55					
				I _{OL} = 64 mA			0.55					
I _I	Control inputs	V _{CC} = 3.6 V, V _I = V _{CC} or GND		±1			±1			μA		
		V _{CC} = 0 or 3.6 V, V _I = 5.5 V		10			10					
	A or B ports‡	V _I = 5.5 V		20			20					
		V _{CC} = 3.6 V, V _I = V _{CC}		1			1					
		V _I = 0		−5			−5					
I _{off}		V _{CC} = 0, V _I or V _O = 0 to 4.5 V					±100			μA		
I _I (hold)	A or B ports	V _{CC} = 3 V		V _I = 0.8 V		75			75			μA
				V _I = 2 V		−75			−75			
		V _{CC} = 3.6 V§, V _I = 0 to 3.6 V					±500					
I _{OZPU}		V _{CC} = 0 to 1.5 V, V _O = 0.5 V to 3 V, $\overline{\text{OE}}$ = don't care		±100*			±100			μA		
I _{OZPD}		V _{CC} = 1.5 V to 0, V _O = 0.5 V to 3 V, $\overline{\text{OE}}$ = don't care		±100*			±100			μA		
I _{CC}		V _{CC} = 3.6 V, I _O = 0, V _I = V _{CC} or GND		Outputs high			0.19			mA		
				Outputs low			5					
				Outputs disabled			0.19					
ΔI _{CC} ¶		V _{CC} = 3 V to 3.6 V, One input at V _{CC} − 0.6 V, Other inputs at V _{CC} or GND		0.2			0.2			mA		
C _i		V _I = 3 V or 0		4			4			pF		
C _{io}		V _O = 3 V or 0		10			10			pF		

* On products compliant to MIL-PRF-38535, this parameter is not production tested.

† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ Unused pins at $V_{CC}\text{ or GND}$

§ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than $V_{CC}\text{ or GND}$.

SN54LVTH16646, SN74LVTH16646

3.3-V ABT 16-BIT BUS TRANSCEIVERS

WITH 3-STATE OUTPUTS

SCBS698E – JULY 1997 – REVISED APRIL 1999

timing requirements over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

			SN54LVTH16646				SN74LVTH16646				UNIT
			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		
			MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
f _{clock}	Clock frequency		150		150		150		150		MHz
t _w	Pulse duration, CLK high or low		3.3		3.3		3.3		3.3		ns
t _{su}	Setup time, A or B before CLKAB↑ or CLKBA↑	Data high	1.2		1.5		1.2		1.5		ns
		Data low	2		2.8		2		2.8		
t _h	Hold time, A or B after CLKAB↑ or CLKBA↑	Data high	0.5		0		0.5		0		ns
		Data low	0.5		0.5		0.5		0.5		

switching characteristics over recommended operating free-air temperature range, $C_L = 50\text{ pF}$ (unless otherwise noted) (see Figure 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54LVTH16646				SN74LVTH16646				UNIT	
			V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		V _{CC} = 2.7 V			
			MIN	MAX	MIN	MAX	MIN	TYP†	MAX	MIN		MAX
f _{max}			150		150		150		150		MHz	
t _{PLH}	CLKBA or CLKAB	A or B	1.3	4.5	5		1.3	2.8	4.2	4.7		ns
t _{PHL}			1.3	4.5	5		1.3	2.8	4.2	4.7		
t _{PLH}	A or B	B or A	1	3.6	4.1		1	2.4	3.4	3.9		ns
t _{PHL}			1	3.6	4.1		1	2.1	3.4	3.9		
t _{PLH}	SBA or SAB‡	A or B	1	4.7	5.6		1	2.8	4.5	5.4		ns
t _{PHL}			1	4.7	5.6		1	3	4.5	5.4		
t _{PZH}	OE	A or B	1	4.5	5.4		1	2.5	4.3	5.2		ns
t _{PZL}			1	4.5	5.4		1	2.6	4.3	5.2		
t _{PHZ}	OE	A or B	2	5.8	6.3		2	4	5.6	6.1		ns
t _{PLZ}			2	5.6	6.3		2	3.6	5.4	6.1		
t _{PZH}	DIR	A or B	1	4.6	5.5		1	3	4.4	5.3		ns
t _{PZL}			1	4.6	5.5		1	3	4.4	5.3		
t _{PHZ}	DIR	A or B	1.5	6	7.1		1.5	3.9	5.7	6.8		ns
t _{PLZ}			1.5	5.5	6		1.5	3.6	5.2	5.7		

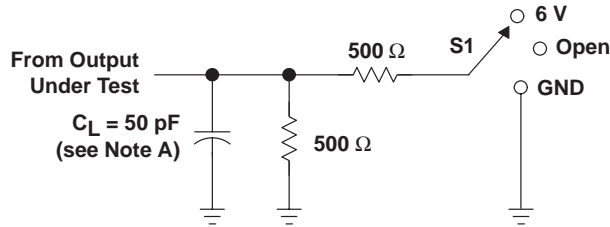
† All typical values are at $V_{CC} = 3.3\text{ V}$, $T_A = 25^\circ\text{C}$.

‡ These parameters are measured with the internal output state of the storage register opposite that of the bus input.

SN54LVTH16646, SN74LVTH16646 3.3-V ABT 16-BIT BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

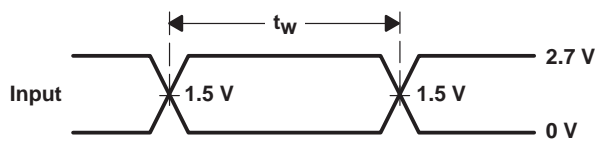
SCBS698E – JULY 1997 – REVISED APRIL 1999

PARAMETER MEASUREMENT INFORMATION

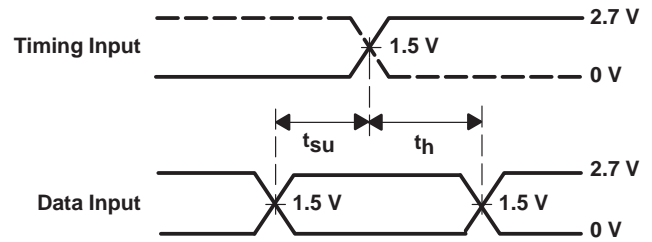


LOAD CIRCUIT

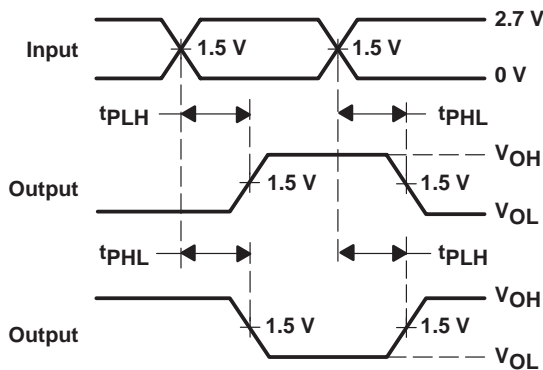
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	6 V
t_{PHZ}/t_{PZH}	GND



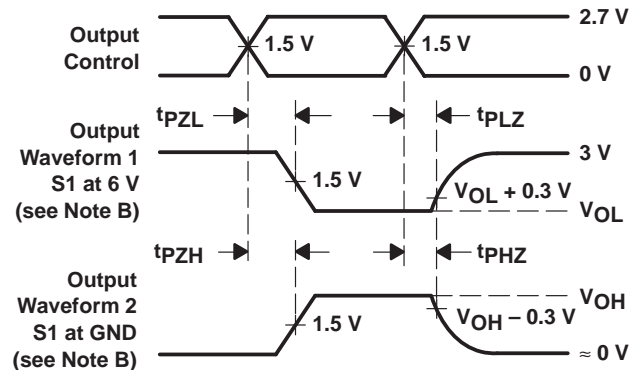
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES:
- A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.